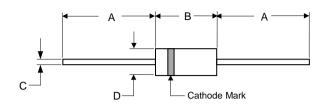


1N4689 THRU 1N4713 Silicon Epitaxial Planar Zener Diodes

Features





DO-35					
DIM	INCHES		MM		
	MIN	MAX	MIN	MAX	
Α	1.083		27.50		
В		0.154		3.90	
С		0.020		0.50	
D		0.075		1.90	

Parameter	Symbol	Value	Unit
Power Dissipation	Ptot	500	mW
Junction Temperature	Tj	175	$^{\circ}$
Storage Temperature Range	T _{stg}	- 65 to + 175	$^{\circ}\!\mathbb{C}$

Characteristics (T_A=25 °C unless otherwise noted)

Туре	Zener Voltage ¹⁾ Vz (V)			Maximum Reverse Current		Maximum Zener Current 2)	
	Nom.	Min.	Max.	at Izт (µА)	Ir (µA)	at V _R (V)	Izм (mA)
1N4689	5.1	4.85	5.35	50	10	3	55
1N4690	5.6	5.32	5.88	50	10	4	50
1N4691	6.2	5.89	6.51	50	10	5	45
1N4692	6.8	6.46	7.14	50	10	5.1	35
1N4693	7.5	7.13	7.88	50	10	5.7	31.8
1N4694	8.2	7.79	8.61	50	1	6.2	29
1N4695	8.7	8.27	9.14	50	1	6.6	27.4
1N4696	9.1	8.65	9.56	50	1	6.9	26.2
1N4697	10	9.5	10.5	50	1	7.6	24.8
1N4698	11	10.45	11.55	50	0.05	8.4	21.6
1N4699	12	11.4	12.6	50	0.05	9.1	20.4
1N4700	13	12.35	13.65	50	0.05	9.8	19
1N4701	14	13.3	14.7	50	0.05	10.6	17.5
1N4702	15	14.25	15.75	50	0.05	11.4	16.3
1N4705	18	17.1	18.9	50	0.05	13.6	13.2
1N4713	30	28.5	31.5	50	0.01	22.8	7.9

Note:

Version: 6.1 www.jgdsemi.com

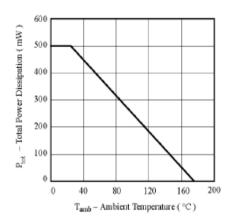
¹⁾ Tested with pulses tp = 20 ms.

²⁾ Maximum Zener current ratings are based on maximum zener voltage of the individual units.

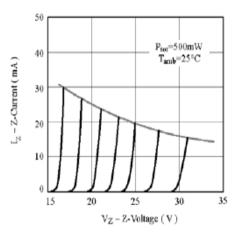


1N4689 THRU 1N4713 Silicon Epitaxial Planar Zener Diodes

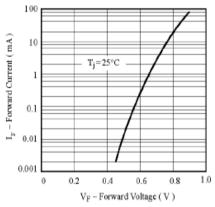
Ratings and Characteristic Curves



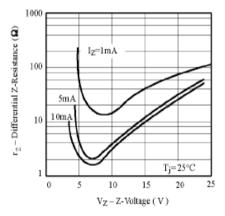
Total Power Dissipation vs. Ambient Temperature



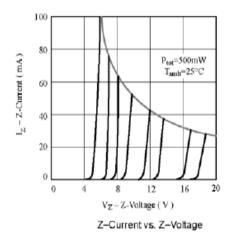
Z-Current vs. Z-Voltage



Forward Current vs. Forward Voltage



Differential Z-Resistance vs. Z-Voltage



Version: 6.1 www.jgdsemi.com



1N4689 THRU 1N4713 Silicon Epitaxial Planar Zener Diodes

Ordering Information

Part No.	Package	Packing Code	Packing
1N4689 THRU 1N4713	DO-35	A50	5000pcs/Ammo

Disclaimer

Specifications of the products displayed herein are subject to change without notice. JGD or anyone on its behalf, assumes no responsibility or liability for any errors inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied,to any intellectual property rights is granted by this document. Except as provided in JGD's terms and conditions of sale for such products, JGD assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of JGD products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or seling these products for use in such applications do so at their own risk and agree to fully indemnify JGD for any damages resulting from such improper use or sale.

Version: 6.1 www.jgdsemi.com